NSN 5961-01-281-5576

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Inclosure Material:

Metal

Overall Length:

0.464 inches

Overall Height:

0.034 inches

Overall Width:

0.464 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1.5 emitter to base voltage, dc and 20.0 collector to base voltage, dc and 12.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

150.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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